



شبكة المعلومات الجامعية

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شبكة المعلومات الجامعية



شبكة المعلومات الجامعية

التوثيق الالكتروني والميكرو فيلم

جامعة عين شمس

التوثيق الالكتروني والميكرو فيلم

قسم

نقسم بالله العظيم أن المادة التي تم توثيقها وتسجيلها
علي هذه الأفلام قد اعدت دون أية تغيرات



يجب أن

تحفظ هذه الأفلام بعيداً عن الغبار

في درجة حرارة من 15 – 20 مئوية ورطوبة نسبية من 20-40 %

To be kept away from dust in dry cool place of
15 – 25c and relative humidity 20-40 %



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بعض الوثائق الأصلية تالفة



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بالرسالة صفحات
لم ترد بالأصل



Assiut University



Faculty of Science

GROWTH AND PHYSICAL PROPERTIES OF POTASSIUM ZINC CHLORIDE MODULATED- FERROELECTRIC CRYSTALS

A THESIS

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By

Mostafa Masaoud Mostafa
B.Sc. Physics

Supervised by

**Prof. Dr. Mohamed Abdel-Aziz
Gaffar**

Prof. of Solid State Physics
Faculty of Science, Assiut University

**Prof. Dr. Abdel-Aziz Abul-Fadl
Abdel-Aziz**

Prof. of Solid State Physics
Faculty of Science, Assiut University

**Prof. Dr. Abdel-Salam Mohamed
Abousehly**

Prof. of Solid State Physics and
Dean of Faculty of Science,
Al Azhar University- Assiut

**Physics Department
Faculty of Science
Assiut University
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APPROVAL SHEET

Name : Mostafa Masaoud Mostafa

Thesis Title : Growth and Physical Properties of
Potassium Zinc Chloride Modulated-
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Degree : Master of Science (Physics)

Courses : 1- Crystal Growth. 2- Crystal Structure.
3- Thermal Analysis 4- Quantum Mechanics.
5- Special Course. 6- Computer Programming.
7- Methods of Experimental Physics.

Supervisors:

1. **Prof. Dr. Mohamed Abd El-Aziz Gaffar** [*Gaffar, M.A.*]
Physics Department, Faculty of Science, Assiut University.
2. **Prof. Dr. Abdel-Aziz Abu-Elfadl** [*A. Abulfadl*]
Physics Department, Faculty of Science, Assiut University.
3. **Prof. Dr. Abd Elsalam Mohamed Abousehly** [*A. Abousehly*]
Dean of Faculty of Science, Al Azhar University, in Assiut.

Examination Committee:

External referees:

1. **Prof. Dr. Mohamed Fathay Ibrahim Kotkata**
Head of Physics Department, Faculty of Science, Ain Shams University.
2. **Prof. Dr. Said Abdel-Aziz Mazin**
Head of Physics Department, Faculty of Science, Zagazig University.

Internal Referees:

1. **Prof. Dr. Mohamed Abd El-Aziz Gaffar** [*Gaffar, M.A.*]
Physics Department, Faculty of Science, Assiut University.
2. **Prof. Dr. Abdel-Salam Mohamed Abousehly** [*A. Abousehly*]
Dean of Faculty of Science, Al Azhar University, in Assiut.

Prof. Dr. Mohamed Taha Ismail

Vice-Dean for Post Graduate Studies and Research Faculty of Science,
Assiut University.

M. T. Ismail

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